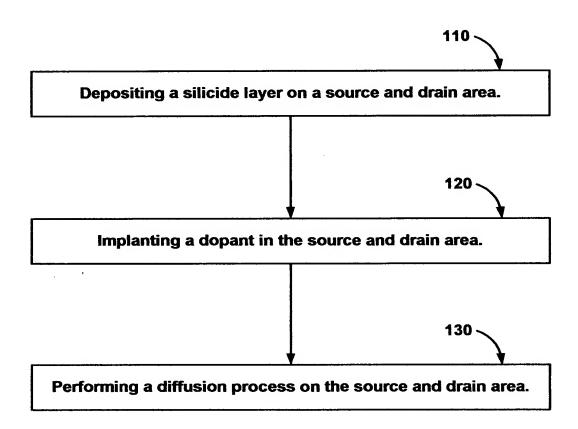
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TITLE: "A FLASH MEMORY CELL DRAIN AND SOURCE FABRICATION SYSTEM AND METHOD"

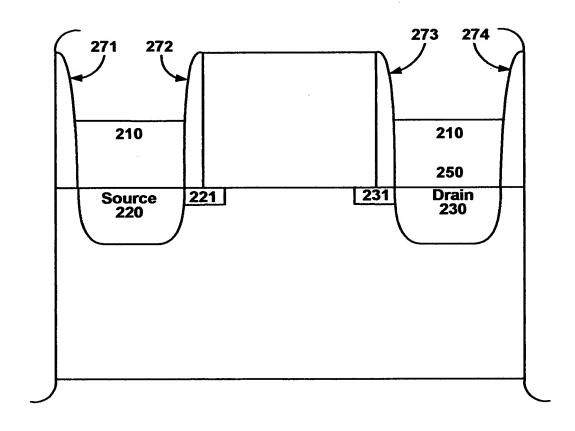
INVENTOR (S): Shenqing Fang Attorney Docket #: AMD-H0634

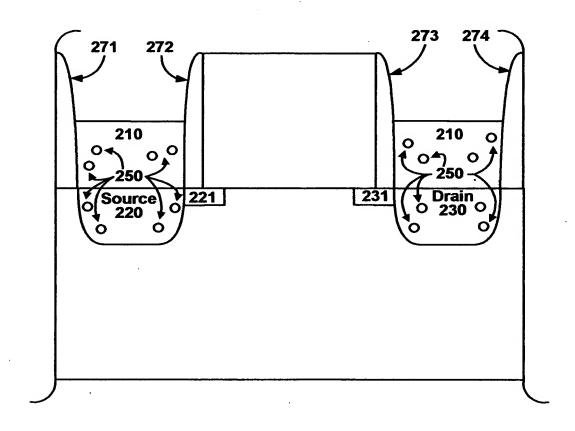
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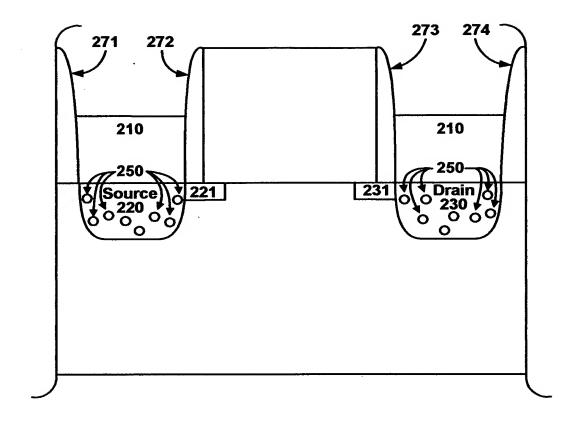
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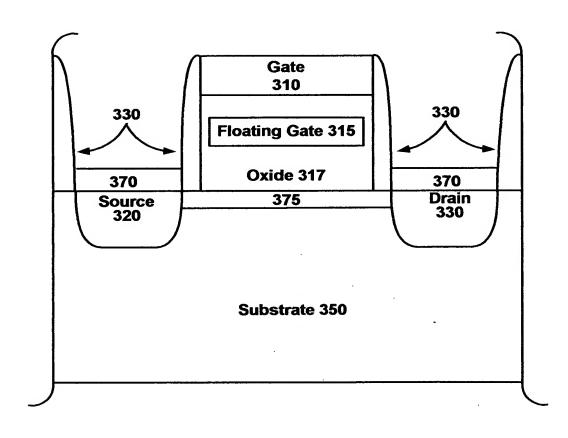


FIG. 3

400

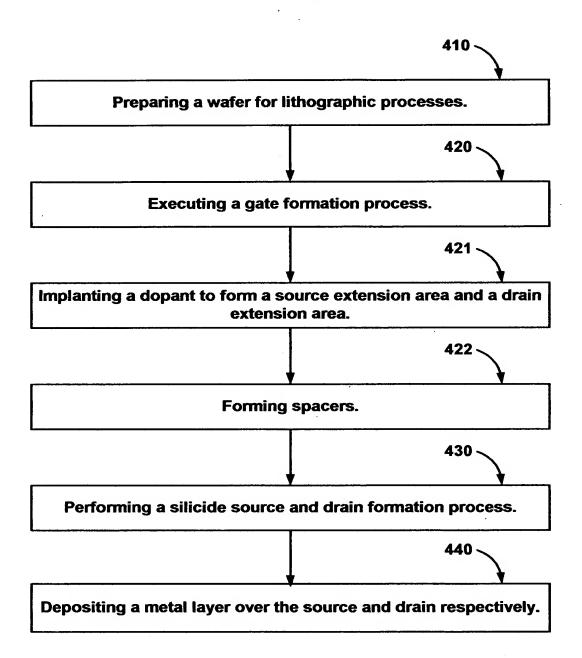


FIG. 4